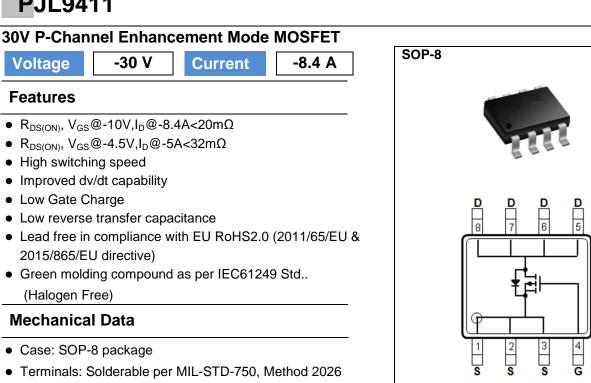
ΡΛΝ	ĴΪΤ
	SEMI CONDUCTOR



• Approx. Weight: 0.0029 ounces, 0.083 grams

Maximum Ratings and Thermal Characteristics (T_A=25[°]C unless otherwise noted)

PARAME	TER	SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-30	V
Gate-Source Voltage		V _{GS}	<u>+</u> 20	V
Continuous Drain Current	T _A =25°C		-8.4	_
	T _A =70°C	I _D	-6.7	A
Pulsed Drain Current (Note 1)		I _{DM}	-33.6	А
Power Dissipation	T _A =25°C		1.7	
	T _A =70°C	P _D	1.1	W
Operating Junction and Storage	Temperature Range	T _J ,T _{STG}	-55~150	°C
Typical Thermal Resistance - Junction to Ambient ^(Note 5)		R _{eJA}	73.5	°C/W





Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =-250uA	-30	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=-250$ uA	-1.0	-1.5	-2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-10V,I _D =-8.4A	-	17	20	mΩ
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =-4.5V,I _D =-5A	-	26	32	mΩ
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-30V,V _{GS} =0V	-	-	-1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Qg	V_{DS} =-15V, I _D =-5A, V_{GS} =-4.5V ^(Note 1,2)	-	11	-	
Gate-Source Charge	Q _{gs}		-	3.2	-	nC
Gate-Drain Charge	Q_gd		-	3.9	-	
Input Capacitance	Ciss	V _{DS} =-15V, V _{GS} =0V, f=1.0MHZ	-	1169	-	
Output Capacitance	Coss		-	180	-	pF
Reverse Transfer Capacitance	Crss		-	132	-	
Turn-On Delay Time	td _(on)	V _{DS} =-15V,I _D =-1A, V _{GS} =-10V, R _G =6Ω	-	5.9	-	
Turn-On Rise Time	tr		-	33	-	ns
Turn-Off Delay Time	td _(off)		-	55	-	
Turn-Off Fall Time	tf		-	34	-	
Drain-Source Diode	1					
Maximum Continuous Drain-Source			_	_	-8.4	A
Diode Forward Current	I _S		-	-	-0.4	~
Diode Forward Voltage	V_{SD}	I _S =-1A, V _{GS} =0V	-	-0.7	-1.0	V

NOTES :

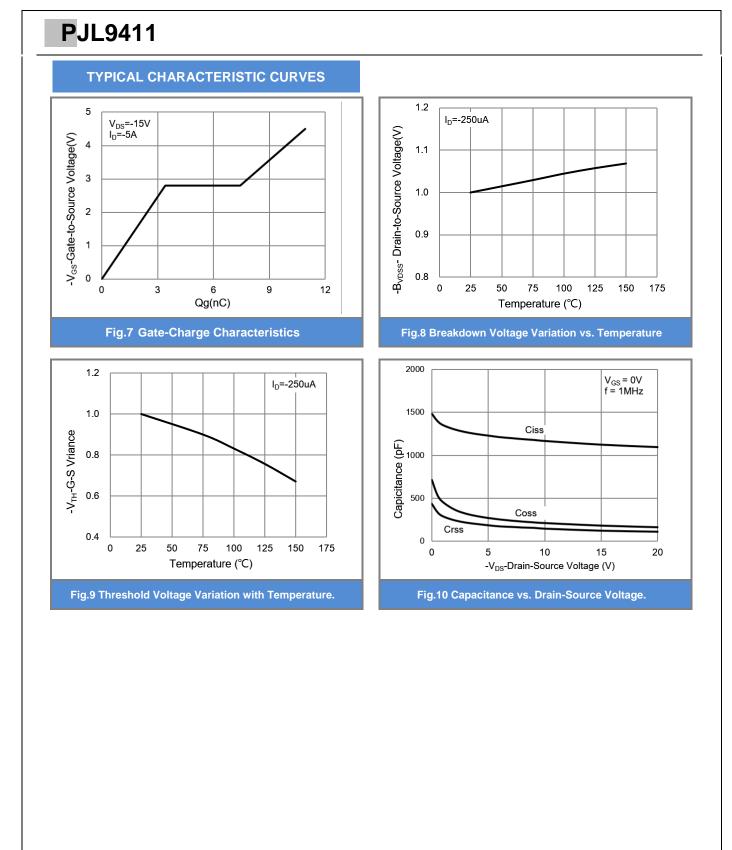
- 1. Pulse width</br>
- 2. Essentially independent of operating temperature typical characteristics.
- 3. The maximum current rating is package limited.
- Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 5. $R_{\Theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





PJL9411 TYPICAL CHARACTERISTIC CURVES 20 20 V_{G\$}=-3.5V V_{DS}=-5V -I_{DS}-Drain-to-S ource Current(A) -I_{DS}-Drain-to-S ource Current(A) 16 16 /_{GS}=-10V,-8V, -5V-4.5V,-4V 12 12 V_{GS}=-3V 8 8 T**」=25°**C T_J=125℃ 4 4 V_{GS}=-2.5V 0 0 0 1 2 3 5 0 4 1 2 3 4 5 -V_{DS}- Drain-to-Source Voltage(V) -V_{GS}-Gate-to-Source Voltage(V) **Fig.1 On-Region Characteristics Fig.2 Transfer Characteristics** 1.8 45 R_{Ds}(on)- On-Resistance (Normalized) $R_{DS}(on)$ - On-Resistance(m Ω) 1.5 35 V_{GS}=-10V, I_D=-8.4A V_{GS}=-4.5V 1.2 25 V_{GS}=-4.5V, I_D=-5A V_{GS}=-10V 0.9 15 0.6 5 0 15 25 50 75 100 125 175 0 5 10 20 150 Temperature (°C) -I_{DS}-Drain-to-Source Current(A) Fig.3 On-Resistance vs. Drain Current Fig.4 On-Resistance vs. Junction temperature 80 10 I_D=-4A -I_{sD}-Source-to-Drain Current(A) $R_{DS}(on)$ - On-Resistance(m Ω) 60 1 40 Tj=125℃ т_і=25°С T_i=125℃ 0.1 20 Tj=25℃ 0 0.01 1 5 3 7 9 0 0.3 0.6 0.9 1.2 -V_{GS}-Gate-to-Source Voltage(V) -V_{SD}-Source-to-Drain Voltage(V) **Fig.6 Body Diode Characteristics**

Fig.5 On-Resistance Variation with VGS.







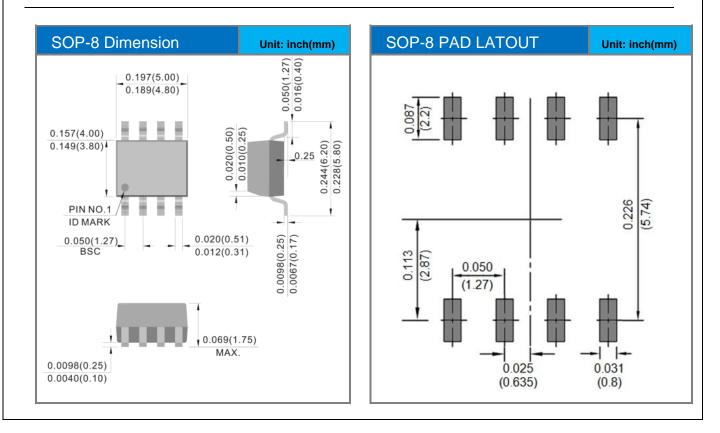




Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJL9411_R2_00001	SOP-8	2.5K pcs / 13" reel	L9411	Halogen free

Packaging Information & Mounting Pad Layout







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